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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	RL78
Core Size	16-Bit
Speed	24MHz
Connectivity	CSI, I <sup>2</sup> C, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	23
Program Memory Size	16KB (16K x 8)
Program Memory Type	FLASH
EEPROM Size	2K x 8
RAM Size	2K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 5.5V
Data Converters	A/D 8x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	30-LSSOP (0.240", 6.10mm Width)
Supplier Device Package	30-LSSOP
Purchase URL	<a href="https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f102aaasp-v0">https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f102aaasp-v0</a>

### 1.3.2 On-chip oscillator characteristics

(1) High-speed on-chip oscillator oscillation frequency of the R5F102 products

Oscillator	Condition	MIN	MAX	Unit
High-speed on-chip oscillator oscillation frequency accuracy	$T_A = -20$ to $+85$ °C	-1.0	+1.0	%
	$T_A = -40$ to $-20$ °C	-1.5	+1.5	
	$T_A = +85$ to $+105$ °C	-2.0	+2.0	

(2) High-speed on-chip oscillator oscillation frequency of the R5F103 products

Oscillator	Condition	MIN	MAX	Unit
High-speed on-chip oscillator oscillation frequency accuracy	$T_A = -40$ to $+85$ °C	-5.0	+5.0	%

### 1.3.3 Peripheral Functions

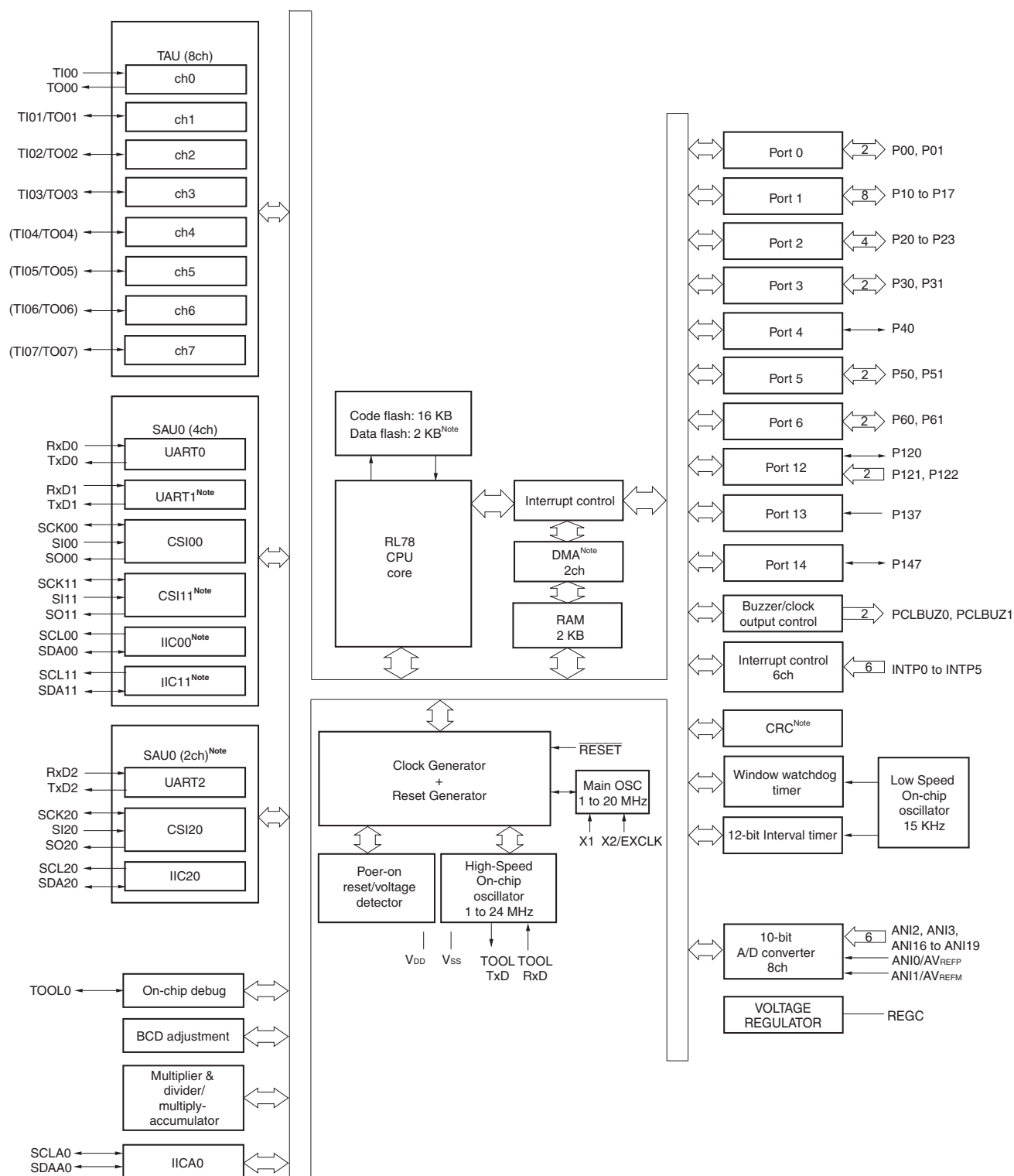
The following are differences in peripheral functions between the R5F102 products and the R5F103 products.

RL78/G12		R5F102 product		R5F103 product	
		20, 24 pin product	30 pin product	20, 24 pin product	30 pin product
Serial interface	UART	1 channel	3 channels	1 channel	
	CSI	2 channels	3 channels	1 channel	
	Simplified I <sup>2</sup> C	2 channels	3 channels	None	
DMA function		2 channels		None	
Safety function	CRC operation	Yes		None	
	RAM guard	Yes		None	
	SFR guard	Yes		None	

## 1.5 Pin Identification

ANI0 to ANI3, ANI16 to ANI22:	Analog input	REGC:	Regulator Capacitance
AVREFM:	Analog Reference Voltage Minus	RESET:	Reset
AVREFP:	Analog reference voltage plus	RxD0 to RxD2:	Receive Data
EXCLK:	External Clock Input (Main System Clock)	SCK00, SCK01, SCK11, SCK20:	Serial Clock Input/Output
INTP0 to INTP5	Interrupt Request From Peripheral	SCL00, SCL01, SCL11, SCL20, SCLA0:	Serial Clock Input/Output
KR0 to KR9:	Key Return	SDA00, SDA01, SDA11, SDA20, SDAA0:	Serial Data Input/Output
P00 to P03:	Port 0	SI00, SI01, SI11, SI20:	Serial Data Input
P10 to P17:	Port 1	SO00, SO01, SO11, SO20:	Serial Data Output
P20 to P23:	Port 2	TI00 to TI07:	Timer Input
P30 to P31:	Port 3	TO00 to TO07:	Timer Output
P40 to P42:	Port 4	TOOL0:	Data Input/Output for Tool
P50, P51:	Port 5	TOOLRxD, TOOLTxD:	Data Input/Output for External Device
P60, P61:	Port 6	TxD0 to TxD2:	Transmit Data
P120 to P122, P125:	Port 12	VDD:	Power supply
P137:	Port 13	VSS:	Ground
P147:	Port 14	X1, X2:	Crystal Oscillator (Main System Clock)
PCLBUZ0, PCLBUZ1:	Programmable Clock Output/ Buzzer Output		

## 1.6.3 30-pin products



**Note** Provided only in the R5F102 products.

**Remark** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). See **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)**.

## 1.7 Outline of Functions

This outline describes the function at the time when Peripheral I/O redirection register (PIOR) is set to 00H.

(1/2)

<R>

Item		20-pin		24-pin		30-pin	
		R5F1026x	R5F1036x	R5F1027x	R5F1037x	R5F102Ax	R5F103Ax
Code flash memory		2 to 16 KB <sup>Note 1</sup>		4 to 16 KB			
Data flash memory		2 KB	—	2 KB	—	2 KB	—
RAM		256 B to 1.5 KB		512 B to 1.5 KB		512 B to 2KB	
Address space		1 MB					
Main system clock	High-speed system clock	X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK) HS (High-speed main) mode : 1 to 20 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (High-speed main) mode : 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (Low-speed main) mode : 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V)					
	High-speed on-chip oscillator clock	HS (High-speed main) mode : 1 to 24 MHz (V <sub>DD</sub> = 2.7 to 5.5 V), HS (High-speed main) mode : 1 to 16 MHz (V <sub>DD</sub> = 2.4 to 5.5 V), LS (Low-speed main) mode : 1 to 8 MHz (V <sub>DD</sub> = 1.8 to 5.5 V)					
Low-speed on-chip oscillator clock		15 kHz (TYP)					
General-purpose register		(8-bit register × 8) × 4 banks					
Minimum instruction execution time		0.04167 μs (High-speed on-chip oscillator clock: f <sub>IH</sub> = 24 MHz operation)					
		0.05 μs (High-speed system clock: f <sub>MX</sub> = 20 MHz operation)					
Instruction set		• Data transfer (8/16 bits) • Adder and subtractor/logical operation (8/16 bits) • Multiplication (8 bits × 8 bits) • Rotate, barrel shift, and bit manipulation (set, reset, test, and Boolean operation), etc.					
I/O port	Total	18		22		26	
	CMOS I/O	12 (N-ch O.D. I/O [V <sub>DD</sub> withstand voltage]: 4)		16 (N-ch O.D. I/O [V <sub>DD</sub> withstand voltage]: 5)		21 (N-ch O.D. I/O [V <sub>DD</sub> withstand voltage]: 9)	
	CMOS input	4		4		3	
	N-ch open-drain I/O (6 V tolerance)	2					
Timer	16-bit timer	4 channels				8 channels	
	Watchdog timer	1 channel					
	12-bit Interval timer	1 channel					
	Timer output	4 channels (PWM outputs: 3 <sup>Note 3</sup> )				8 channels (PWM outputs: 7 <sup>Note 3</sup> , <sup>Note 2</sup> )	

**Notes** 1. The self-programming function cannot be used in the R5F10266 and R5F10366.

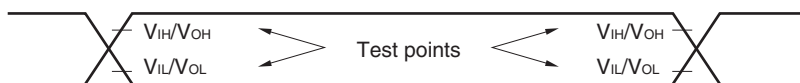
2. The maximum number of channels when PIOR0 is set to 1.

3. The number of PWM outputs varies depending on the setting of channels in use (the number of masters and slaves). (See **6.9.3 Operation as multiple PWM output function.**)

**Caution** When the flash memory is rewritten via a user program, the code flash area and RAM area are used because each library is used. When using the library, refer to RL78 Family Flash Self Programming Library Type01 User's Manual and RL78 Family Data Flash Library Type04 User's Manual.

## 2.5 Peripheral Functions Characteristics

### AC Timing Test Point



### 2.5.1 Serial array unit

#### (1) During communication at same potential (UART mode)

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	
Transfer rate				$f_{MCK}/6$		$f_{MCK}/6$	bps
Note 1		Theoretical value of the maximum transfer rate $f_{CLK} = f_{MCK}$ <sup>Note2</sup>		4.0		1.3	Mbps

**Notes** 1. Transfer rate in the SNOOZE mode is 4800 bps only.

2. The maximum operating frequencies of the CPU/peripheral hardware clock ( $f_{CLK}$ ) are:

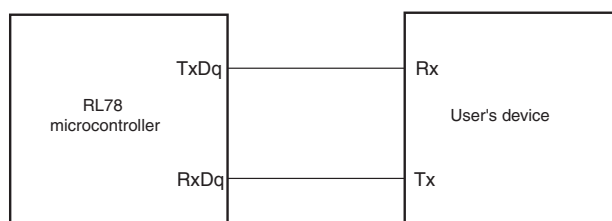
HS (high-speed main) mode: 24 MHz ( $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ )

16 MHz ( $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ )

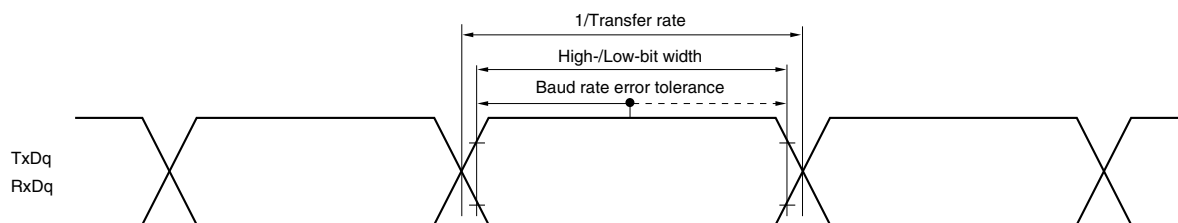
LS (low-speed main) mode: 8 MHz ( $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ )

**Caution** Select the normal input buffer for the RxDq pin and the normal output mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg).

#### UART mode connection diagram (during communication at same potential)



#### UART mode bit width (during communication at same potential) (reference)



**Remarks** 1. q: UART number (q = 0 to 2), g: PIM, POM number (g = 0, 1)

2.  $f_{MCK}$ : Serial array unit operation clock frequency

(Operation clock to be set by the serial clock select register m (SPSm) and the CKSmn bit of serial mode register mn (SMRmn).

m: Unit number, n: Channel number (mn = 00 to 03, 10, 11))

- Remarks** 1. p: CSI number (p = 00, 01, 11, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0, 1, 3: "1, 3" is only for the R5F102 products.)
2.  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the serial clock select register m (SPSm) and the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0, 1), n: Channel number (n = 0, 1, 3: "1, 3" is only for the R5F102 products.))

**(5) During communication at same potential (simplified I<sup>2</sup>C mode)**

**( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	HS (high-speed main) Mode LS (low-speed main) Mode		Unit
			MIN.	MAX.	
SCLr clock frequency	$f_{SCL}$	$1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$		400 <sup>Note 1</sup>	kHz
		$1.8\text{ V} \leq V_{DD} < 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 5\text{ k}\Omega$		300 <sup>Note 1</sup>	kHz
Hold time when SCLr = "L"	$t_{LOW}$	$1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	1150		ns
		$1.8\text{ V} \leq V_{DD} < 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 5\text{ k}\Omega$	1550		ns
Hold time when SCLr = "H"	$t_{HIGH}$	$1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	1150		ns
		$1.8\text{ V} \leq V_{DD} < 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 5\text{ k}\Omega$	1550		ns
Data setup time (reception)	$t_{SU:DAT}$	$1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	$1/f_{MCK} + 145$ <sup>Note 2</sup>		ns
		$1.8\text{ V} \leq V_{DD} < 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 5\text{ k}\Omega$	$1/f_{MCK} + 230$ <sup>Note 2</sup>		ns
Data hold time (transmission)	$t_{HD:DAT}$	$1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 3\text{ k}\Omega$	0	355	ns
		$1.8\text{ V} \leq V_{DD} < 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 5\text{ k}\Omega$	0	405	ns

- Notes** 1. The value must also be equal to or less than  $f_{MCK}/4$ .
2. Set  $t_{SU:DAT}$  so that it will not exceed the hold time when SCLr = "L" or SCLr = "H".

**Caution** Select the N-ch open drain output ( $V_{DD}$  tolerance) mode for SDAr by using port output mode register h (POMh).

(Remarks are listed on the next page.)

5. This value as an example is calculated when the conditions described in the “Conditions” column are met. Refer to **Note 4** above to calculate the maximum transfer rate under conditions of the customer.

6. The smaller maximum transfer rate derived by using f<sub>MCK</sub>/6 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 2.7 V ≤ V<sub>DD</sub> < 4.0 V and 2.3 V ≤ V<sub>b</sub> ≤ 2.7 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\} \times 3} \quad [\text{bps}]$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 [\%]$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides.

7. This value as an example is calculated when the conditions described in the “Conditions” column are met. Refer to **Note 6** above to calculate the maximum transfer rate under conditions of the customer.

8. The smaller maximum transfer rate derived by using f<sub>MCK</sub>/6 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 1.8 V ≤ V<sub>DD</sub> < 3.3 V, 1.6 V ≤ V<sub>b</sub> ≤ 2.0 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\} \times 3} \quad [\text{bps}]$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 [\%]$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides.

9. This value as an example is calculated when the conditions described in the “Conditions” column are met. Refer to **Note 8** above to calculate the maximum transfer rate under conditions of the customer.

**Caution** Select the TTL input buffer for the RxDq pin and the N-ch open drain output (V<sub>DD</sub> tolerance) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.



**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (2/3)****( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	
Slp setup time (to SCKp $\uparrow$ ) <sup>Note 1</sup>	$t_{SIK1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	81		479		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	177		479		ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ <sup>Note 2</sup> , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	479		479		ns
Slp hold time (from SCKp $\uparrow$ ) <sup>Note 1</sup>	$t_{KSI1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	19		19		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	19		19		ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ <sup>Note 2</sup> , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	19		19		ns
Delay time from SCKp $\downarrow$ to SOp output <sup>Note 1</sup>	$t_{KSO1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$		100		100	ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$		195		195	ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ <sup>Note 2</sup> , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$		483		483	ns

**Notes** 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.2. Use it with  $V_{DD} \geq V_b$ .

(Cautions and Remarks are listed on the next page.)

**(10) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I<sup>2</sup>C mode)****( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	
SCLr clock frequency	$f_{SCL}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$		400 <sup>Note1</sup>		300 <sup>Note1</sup>	kHz
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$		400 <sup>Note1</sup>		300 <sup>Note1</sup>	kHz
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , <sup>Note2</sup> $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$		300 <sup>Note1</sup>		300 <sup>Note1</sup>	kHz
Hold time when SCLr = "L"	$t_{LOW}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$	1150		1550		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	1150		1550		ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , <sup>Note2</sup> $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	1550		1550		ns
Hold time when SCLr = "H"	$t_{HIGH}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$	675		610		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	600		610		ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , <sup>Note2</sup> $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	610		610		ns
Data setup time (reception)	$t_{SU:DAT}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$	$1/f_{MCK}$ + 190 <sup>Note3</sup>		$1/f_{MCK}$ + 190 <sup>Note3</sup>		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	$1/f_{MCK}$ + 190 <sup>Note3</sup>		$1/f_{MCK}$ + 190 <sup>Note3</sup>		ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , <sup>Note2</sup> $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	$1/f_{MCK}$ + 190 <sup>Note3</sup>		$1/f_{MCK}$ + 190 <sup>Note3</sup>		ns
Data hold time (transmission)	$t_{HD:DAT}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.8\text{ k}\Omega$	0	355	0	355	ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 100\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	0	355	0	355	ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ , <sup>Note2</sup> $C_b = 100\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	0	405	0	405	ns

**Notes** 1. The value must also be equal to or less than  $f_{MCK}/4$ .2. Use it with  $V_{DD} \geq V_b$ .3. Set  $t_{SU:DAT}$  so that it will not exceed the hold time when SCLr = "L" or SCLr = "H".

**Cautions** 1. Select the TTL input buffer and the N-ch open drain output ( $V_{DD}$  tolerance) mode for the SDAr pin and the N-ch open drain output ( $V_{DD}$  tolerance) mode for the SCLr pin by using port input mode register 1 (PIM1) and port output mode register 1 (POM1). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

2. IIC01 and IIC11 cannot communicate at different potential.

(Remarks are listed on the next page.)

**LVD detection voltage of interrupt & reset mode****( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $V_{PDR} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Interrupt and reset mode	V <sub>LVD0</sub>	V <sub>POC2</sub> , V <sub>POC1</sub> , V <sub>POC0</sub> = 0, 0, 1, falling reset voltage		1.80	1.84	1.87	V
	V <sub>LVD1</sub>	LVIS1, LVIS0 = 1, 0	Rising reset release voltage	1.94	1.98	2.02	V
			Falling interrupt voltage	1.90	1.94	1.98	V
	V <sub>LVD2</sub>	LVIS1, LVIS0 = 0, 1	Rising reset release voltage	2.05	2.09	2.13	V
			Falling interrupt voltage	2.00	2.04	2.08	V
	V <sub>LVD3</sub>	LVIS1, LVIS0 = 0, 0	Rising reset release voltage	3.07	3.13	3.19	V
			Falling interrupt voltage	3.00	3.06	3.12	V
	V <sub>LVD0</sub>	V <sub>POC2</sub> , V <sub>POC1</sub> , V <sub>POC0</sub> = 0, 1, 0, falling reset voltage		2.40	2.45	2.50	V
	V <sub>LVD1</sub>	LVIS1, LVIS0 = 1, 0	Rising reset release voltage	2.56	2.61	2.66	V
			Falling interrupt voltage	2.50	2.55	2.60	V
	V <sub>LVD2</sub>	LVIS1, LVIS0 = 0, 1	Rising reset release voltage	2.66	2.71	2.76	V
			Falling interrupt voltage	2.60	2.65	2.70	V
	V <sub>LVD3</sub>	LVIS1, LVIS0 = 0, 0	Rising reset release voltage	3.68	3.75	3.82	V
			Falling interrupt voltage	3.60	3.67	3.74	V
	V <sub>LVD0</sub>	V <sub>POC2</sub> , V <sub>POC1</sub> , V <sub>POC0</sub> = 0, 1, 1, falling reset voltage		2.70	2.75	2.81	V
	V <sub>LVD1</sub>	LVIS1, LVIS0 = 1, 0	Rising reset release voltage	2.86	2.92	2.97	V
			Falling interrupt voltage	2.80	2.86	2.91	V
	V <sub>LVD2</sub>	LVIS1, LVIS0 = 0, 1	Rising reset release voltage	2.96	3.02	3.08	V
			Falling interrupt voltage	2.90	2.96	3.02	V
	V <sub>LVD3</sub>	LVIS1, LVIS0 = 0, 0	Rising reset release voltage	3.98	4.06	4.14	V
			Falling interrupt voltage	3.90	3.98	4.06	V

**2.6.5 Power supply voltage rising slope characteristics****( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power supply voltage rising slope	S <sub>VDD</sub>				54	V/ms

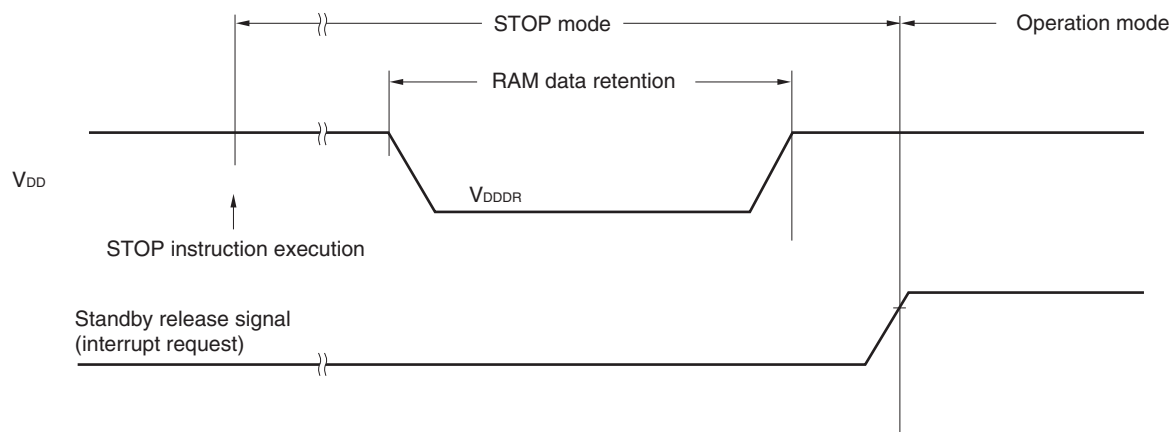
**Caution** Make sure to keep the internal reset state by the LVD circuit or an external reset until  $V_{DD}$  reaches the operating voltage range shown in 28.4 AC Characteristics.

## &lt;R&gt; 2.7 Data Memory STOP Mode Low Supply Voltage Data Retention Characteristics

**( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention supply voltage	$V_{DDDR}$		1.46 <sup>Note</sup>		5.5	V

<R> **Note** This depends on the POR detection voltage. For a falling voltage, data in RAM are retained until the voltage reaches the level that triggers a POR reset but not once it reaches the level at which a POR reset is generated.



## 2.8 Flash Memory Programming Characteristics

**( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

<R>	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
	System clock frequency	f <sub>CLK</sub>		1		24	MHz
	Code flash memory rewritable times <small>Notes 1, 2, 3</small>	C <sub>erwr</sub>	Retained for 20 years T <sub>A</sub> = 85°C	1,000			Times
	Data flash memory rewritable times <small>Notes 1, 2, 3</small>		Retained for 1 year T <sub>A</sub> = 25°C		1,000,000		
			Retained for 5 years T <sub>A</sub> = 85°C	100,000			
			Retained for 20 years T <sub>A</sub> = 85°C	10,000			

- Notes**
- 1 erase + 1 write after the erase is regarded as 1 rewrite. The retaining years are until next rewrite after the rewrite.
  2. When using flash memory programmer and Renesas Electronics self programming library
  3. These are the characteristics of the flash memory and the results obtained from reliability testing by Renesas Electronics Corporation.

## 3.3 DC Characteristics

## 3.3.1 Pin characteristics

(T<sub>A</sub> = -40 to +105°C, 2.4 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V)

(1/4)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output current, high <sup>Note 1</sup>	I <sub>OH1</sub>	20-, 24-pin products: Per pin for P00 to P03 <sup>Note 4</sup> , P10 to P14, P40 to P42  30-pin products: Per pin for P00, P01, P10 to P17, P30, P31, P40, P50, P51, P120, P147			-3.0 <sup>Note 2</sup>	mA
		20-, 24-pin products: Total of P40 to P42	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V		-9.0	mA
			2.7 V ≤ V <sub>DD</sub> < 4.0 V		-6.0	mA
		30-pin products: Total of P00, P01, P40, P120 (When duty ≤ 70% <sup>Note 3</sup> )	2.4 V ≤ V <sub>DD</sub> < 2.7 V		-4.5	mA
		20-, 24-pin products: Total of P00 to P03 <sup>Note 4</sup> , P10 to P14	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V		-27.0	mA
			2.7 V ≤ V <sub>DD</sub> < 4.0 V		-18.0	mA
		30-pin products: Total of P10 to P17, P30, P31, P50, P51, P147 (When duty ≤ 70% <sup>Note 3</sup> )	2.4 V ≤ V <sub>DD</sub> < 2.7 V		-10.0	mA
		Total of all pins (When duty ≤ 70% <sup>Note 3</sup> )			-36.0	mA
	I <sub>OH2</sub>	Per pin for P20 to P23			-0.1	mA
		Total of all pins			-0.4	mA

**Notes** 1. value of current at which the device operation is guaranteed even if the current flows from the V<sub>DD</sub> pin to an output pin.

2. However, do not exceed the total current value.

3. The output current value under conditions where the duty factor ≤ 70%.

If duty factor > 70%: The output current value can be calculated with the following expression (where n represents the duty factor as a percentage).

- Total output current of pins = (I<sub>OH</sub> × 0.7)/(n × 0.01)

<Example> Where n = 80% and I<sub>OH</sub> = -10.0 mA

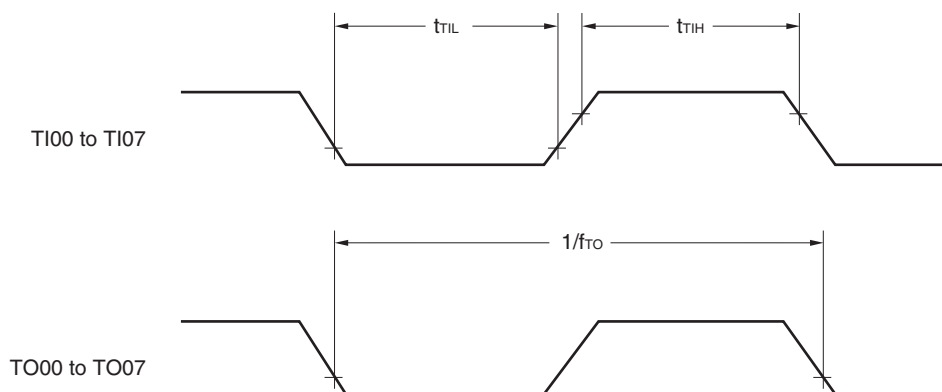
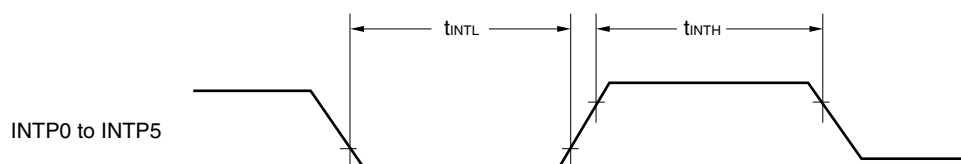
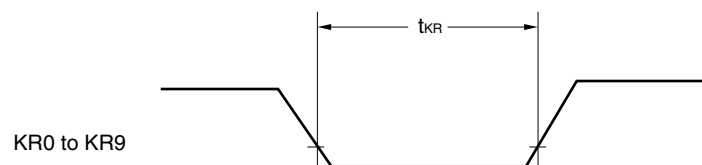
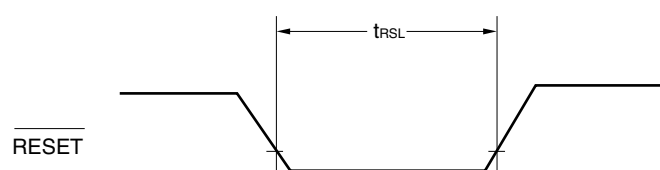
$$\text{Total output current of pins} = (-10.0 \times 0.7)/(80 \times 0.01) \cong -8.7 \text{ mA}$$

However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

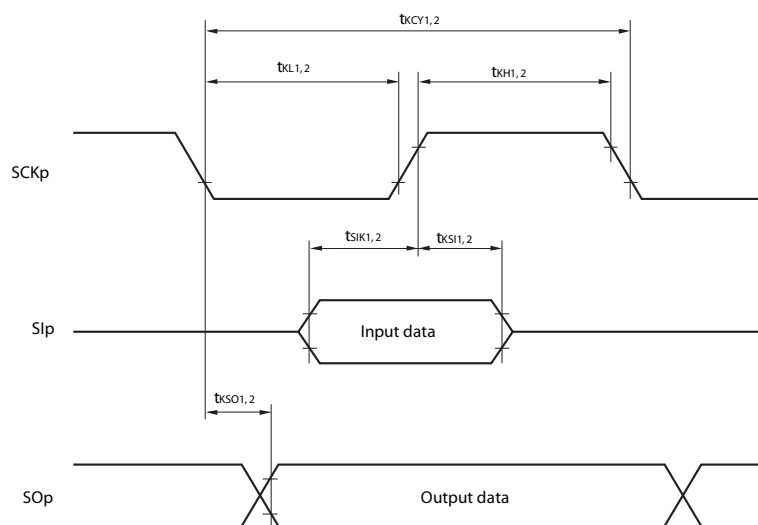
4. 24-pin products only.

**Caution** P10 to P12 and P41 for 20-pin products, P01, P10 to P12, and P41 for 24-pin products, and P00, P10 to P15, P17, and P50 for 30-pin products do not output high level in N-ch open-drain mode.

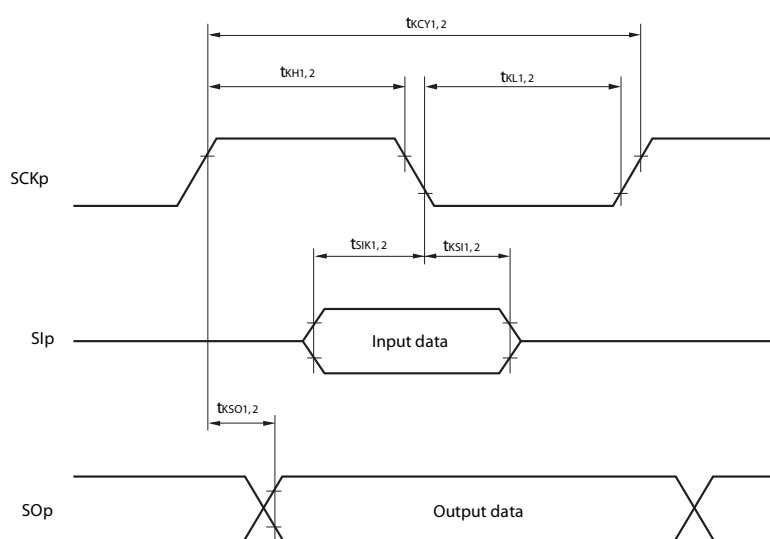
**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

**TI/TO Timing****Interrupt Request Input Timing****Key Interrupt Input Timing****RESET Input Timing**

**CSI mode serial transfer timing (during communication at same potential)**  
**(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)**



**CSI mode serial transfer timing (during communication at same potential)**  
**(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**



- Remarks**
1. p: CSI number (p = 00, 01, 11, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0, 1, 3)
  2.  $f_{\text{MCK}}$ : Serial array unit operation clock frequency  
 (Operation clock to be set by the serial clock select register m (SPSm) and the CKSmn bit of serial mode register mn (SMRmn). m: Unit number (m = 0, 1), n: Channel number (n = 0, 1, 3))

**(5) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

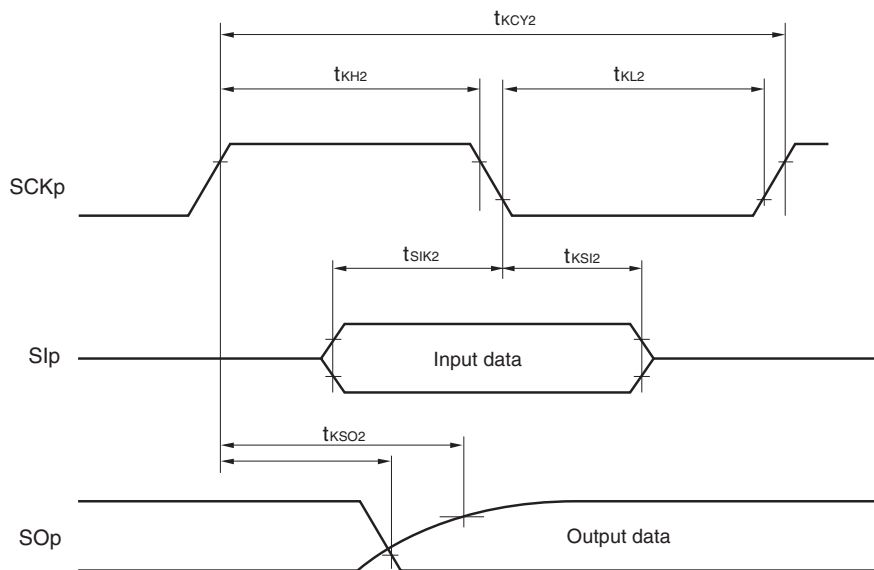
Parameter	Symbol	Conditions		HS (high-speed main) Mode		Unit
				MIN.	MAX.	
Transfer rate <small>Note 4</small>		Reception	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$		$f_{MCK}/12$ <small>Note 1</small>	bps
			Theoretical value of the maximum transfer rate $f_{MCK} = f_{CLK}$ <small>Note 2</small>		2.0	Mbps
			$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$		$f_{MCK}/12$ <small>Note 1</small>	bps
			Theoretical value of the maximum transfer rate $f_{MCK} = f_{CLK}$ <small>Note 2</small>		2.0	Mbps
		Transmission	$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$		$f_{MCK}/12$ <small>Note 1</small>	bps
			Theoretical value of the maximum transfer rate $f_{MCK} = f_{CLK}$ <small>Note 2</small>		2.0	Mbps
			$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$		<b>Note 3</b>	bps
			Theoretical value of the maximum transfer rate $C_b = 50\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$ , $V_b = 2.7\text{ V}$		2.0 <small>Note 4</small>	Mbps
			$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$		<b>Note 5</b>	bps
			Theoretical value of the maximum transfer rate $C_b = 50\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$ , $V_b = 2.3\text{ V}$		1.2 <small>Note 6</small>	Mbps
			$2.4\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$		<b>Notes 2, 7</b>	bps
			Theoretical value of the maximum transfer rate $C_b = 50\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$ , $V_b = 1.6\text{ V}$		0.43 <small>Note 8</small>	Mbps

**Notes 1.** Transfer rate in the SNOOZE mode is 4800 bps only.**2.** The maximum operating frequencies of the CPU/peripheral hardware clock ( $f_{CLK}$ ) are:HS (high-speed main) mode: 24 MHz ( $2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ )16 MHz ( $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ )**3.** The smaller maximum transfer rate derived by using  $f_{MCK}/12$  or the following expression is the valid maximum transfer rate.Expression for calculating the transfer rate when  $4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$  and  $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ 

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\} \times 3} \quad [\text{bps}]$$



**CSI mode serial transfer timing (slave mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)**



**Remark** p: CSI number (p = 00, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0)

### 3.6 Analog Characteristics

#### 3.6.1 A/D converter characteristics

##### Classification of A/D converter characteristics

Input channel	Reference Voltage		
	Reference voltage (+) = $AV_{REFP}$ Reference voltage (-) = $AV_{REFM}$	Reference voltage (+) = $V_{DD}$ Reference voltage (-) = $V_{SS}$	Reference voltage (+) = $V_{BGR}$ Reference voltage (-) = $AV_{REFM}$
ANI0 to ANI3	Refer to 29.6.1 (1).	Refer to 29.6.1 (3).	Refer to 29.6.1 (4).
ANI16 to ANI22	Refer to 29.6.1 (2).		
Internal reference voltage Temperature sensor output voltage	Refer to 29.6.1 (1).		—

(1) When reference voltage (+) =  $AV_{REFP}/ANI0$  ( $ADREFP1 = 0$ ,  $ADREFP0 = 1$ ), reference voltage (-) =  $AV_{REFM}/ANI1$  ( $ADREFM = 1$ ), target pin: ANI2, ANI3, internal reference voltage, and temperature sensor output voltage

( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq AV_{REFP} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ , Reference voltage (+) =  $AV_{REFP}$ , Reference voltage (-) =  $AV_{REFM} = 0\text{ V}$ )

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	RES		8		10	bit
Overall error <sup>Note 1</sup>	AINL	10-bit resolution $AV_{REFP} = V_{DD}$ <sup>Note 3</sup>		1.2	$\pm 3.5$	LSB
Conversion time	$t_{CONV}$	10-bit resolution Target pin: ANI2, ANI3	$3.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	2.125	39	$\mu\text{s}$
			$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	3.1875	39	$\mu\text{s}$
			$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	17	39	$\mu\text{s}$
		10-bit resolution Target pin: Internal reference voltage, and temperature sensor output voltage (HS (high-speed main) mode)	$3.6\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	2.375	39	$\mu\text{s}$
			$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	3.5625	39	$\mu\text{s}$
			$2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	17	39	$\mu\text{s}$
Zero-scale error <sup>Notes 1, 2</sup>	EZS	10-bit resolution $AV_{REFP} = V_{DD}$ <sup>Note 3</sup>			$\pm 0.25$	%FSR
Full-scale error <sup>Notes 1, 2</sup>	EFS	10-bit resolution $AV_{REFP} = V_{DD}$ <sup>Note 3</sup>			$\pm 0.25$	%FSR
Integral linearity error <sup>Note 1</sup>	ILE	10-bit resolution $AV_{REFP} = V_{DD}$ <sup>Note 3</sup>			$\pm 2.5$	LSB
Differential linearity error <sup>Note 1</sup>	DLE	10-bit resolution $AV_{REFP} = V_{DD}$ <sup>Note 3</sup>			$\pm 1.5$	LSB
Analog input voltage	$V_{AIN}$	ANI2, ANI3	0		$AV_{REFP}$	V
		Internal reference voltage (HS (high-speed main) mode)	$V_{BGR}$ <sup>Note 4</sup>			V
		Temperature sensor output voltage (HS (high-speed main) mode)	$V_{TMPS25}$ <sup>Note 4</sup>			V

(Notes are listed on the next page.)

## 3.6.4 LVD circuit characteristics

**LVD Detection Voltage of Reset Mode and Interrupt Mode****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $V_{PDR} \leq V_{DD} \leq 5.5$  V,  $V_{SS} = 0$  V)**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Detection supply voltage	$V_{LVD0}$	Power supply rise time	3.90	4.06	4.22	V
		Power supply fall time	3.83	3.98	4.13	V
	$V_{LVD1}$	Power supply rise time	3.60	3.75	3.90	V
		Power supply fall time	3.53	3.67	3.81	V
	$V_{LVD2}$	Power supply rise time	3.01	3.13	3.25	V
		Power supply fall time	2.94	3.06	3.18	V
	$V_{LVD3}$	Power supply rise time	2.90	3.02	3.14	V
		Power supply fall time	2.85	2.96	3.07	V
	$V_{LVD4}$	Power supply rise time	2.81	2.92	3.03	V
		Power supply fall time	2.75	2.86	2.97	V
	$V_{LVD5}$	Power supply rise time	2.70	2.81	2.92	V
		Power supply fall time	2.64	2.75	2.86	V
	$V_{LVD6}$	Power supply rise time	2.61	2.71	2.81	V
		Power supply fall time	2.55	2.65	2.75	V
	$V_{LVD7}$	Power supply rise time	2.51	2.61	2.71	V
		Power supply fall time	2.45	2.55	2.65	V
Minimum pulse width	$t_{LW}$		300			$\mu\text{s}$
Detection delay time					300	$\mu\text{s}$

**LVD detection voltage of interrupt & reset mode****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $V_{PDR} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Interrupt and reset mode	V <sub>LVDD0</sub>	V <sub>POC2</sub> , V <sub>POC1</sub> , V <sub>POC1</sub> = 0, 1, 1, falling reset voltage		2.64	2.75	2.86	V
	V <sub>LVDD1</sub>	LVIS1, LVIS0 = 1, 0	Rising reset release voltage	2.81	2.92	3.03	V
			Falling interrupt voltage	2.75	2.86	2.97	V
	V <sub>LVDD2</sub>	LVIS1, LVIS0 = 0, 1	Rising reset release voltage	2.90	3.02	3.14	V
			Falling interrupt voltage	2.85	2.96	3.07	V
	V <sub>LVDD3</sub>	LVIS1, LVIS0 = 0, 0	Rising reset release voltage	3.90	4.06	4.22	V
			Falling interrupt voltage	3.83	3.98	4.13	V

**3.6.5 Power supply voltage rising slope characteristics****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power supply voltage rising slope	S <sub>VDD</sub>				54	V/ms

**Caution** Make sure to keep the internal reset state by the LVD circuit or an external reset until  $V_{DD}$  reaches the operating voltage range shown in 29.4 AC Characteristics.

## 3.9 Dedicated Flash Memory Programmer Communication (UART)

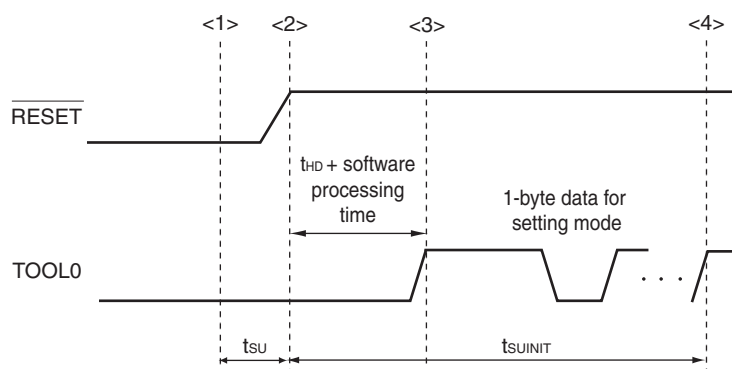
**( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate		During serial programming	115,200		1,000,000	bps

## 3.10 Timing of Entry to Flash Memory Programming Modes

**( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Time to complete the communication for the initial setting after the external reset is released	$t_{\text{SUNIT}}$	POR and LVD reset are released before external release			100	ms
Time to release the external reset after the TOOL0 pin is set to the low level	$t_{\text{SU}}$	POR and LVD reset are released before external release	10			$\mu\text{s}$
Time to hold the TOOL0 pin at the low level after the external reset is released (excluding the processing time of the firmware to control the flash memory)	$t_{\text{HD}}$	POR and LVD reset are released before external release	1			ms



- <1> The low level is input to the TOOL0 pin.
- <2> The external reset is released (POR and LVD reset must be released before the external reset is released.).
- <3> The TOOL0 pin is set to the high level.
- <4> Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

**Remark**  $t_{\text{SUNIT}}$ : Communication for the initial setting must be completed within 100 ms after the external reset is released during this period.

$t_{\text{SU}}$ : Time to release the external reset after the TOOL0 pin is set to the low level

$t_{\text{HD}}$ : Time to hold the TOOL0 pin at the low level after the external reset is released (excluding the processing time of the firmware to control the flash memory)